

# NPN SILICON GERMANIUM RF TRANSISTOR NESG3032M14

# NPN SIGE RF TRANSISTOR FOR LOW NOISE, HIGH-GAIN AMPLIFICATION 4-PIN LEAD-LESS MINIMOLD (M14, 1208 PACKAGE)

#### **FEATURES**

- The device is an ideal choice for low noise, high-gain amplification
   NF = 0.6 dB TYP. @ VcE = 2 V, Ic = 6 mA, f = 2.0 GHz
- Maximum stable power gain: MSG = 20.5 dB TYP. @ VcE = 2 V, Ic = 15 mA, f = 2.0 GHz
- SiGe HBT technology (UHS3) adopted: fmax = 110 GHz
- · 4-pin lead-less minimold (M14, 1208 package)

#### ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
NESG3032M14	NESG3032M14-A	4-pin lead-less minimold (M14, 1208 package)	50 pcs (Non reel)	8 mm wide embossed taping     Pin 1 (Collector), Pin 4 (Emitter) face the
NESG3032M14-T3	NESG3032M14-T3-A	(Pb-Free)	10 kpcs/reel	perforation side of the tape

**Remark** To order evaluation samples, contact your nearby sales office. Unit sample quantity is 50 pcs.

### ABSOLUTE MAXIMUM RATINGS ( $T_A = +25$ °C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	12.0	V
Collector to Emitter Voltage	Vceo	4.3	V
Emitter to Base Voltage	VEBO	1.5	V
Collector Current	lc	35	mA
Total Power Dissipation	Ptot Note	150	mW
Junction Temperature	Tj	150	°C
Storage Temperature	T <sub>stg</sub>	-65 to +150	°C

Note Mounted on 1.08 cm<sup>2</sup> × 1.0 mm (t) glass epoxy PWB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

# **ELECTRICAL CHARACTERISTICS (TA = +25°C)**

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	Ісво	VcB = 5 V, IE = 0 mA	-	-	100	nA
Emitter Cut-off Current	Іво	Veb = 1 V, Ic = 0 mA	-	-	100	nA
DC Current Gain	hfe Note 1	Vce = 2 V, Ic = 6 mA	220	300	380	_
RF Characteristics						
Insertion Power Gain	S <sub>21e</sub>   <sup>2</sup>	Vce = 2 V, Ic = 15 mA, f = 2.0 GHz	15.0	17.5	-	dB
Noise Figure	NF	$V_{CE} = 2 \text{ V}, \text{ Ic} = 6 \text{ mA}, \text{ f} = 2.0 \text{ GHz}, $ $Z_{S} = Z_{Sopt}, Z_{L} = Z_{Lopt}$	-	0.60	0.85	dB
Associated Gain	Ga	$V_{CE} = 2 \text{ V}, \text{ Ic} = 6 \text{ mA}, \text{ f} = 2.0 \text{ GHz}, $ $Z_{S} = Z_{Sopt}, Z_{L} = Z_{Lopt}$	-	17.5	-	dB
Reverse Transfer Capacitance	Cre Note 2	VcB = 2 V, IE = 0 mA, f = 1 MHz	-	0.15	0.25	pF
Maximum Stable Power Gain	MSG <sup>Note</sup>	VcE = 2 V, Ic = 15 mA, f = 2.0 GHz	17.5	20.5	-	dB
Gain 1 dB Compression Output Power	Po (1 dB)	$\begin{split} \text{V}_{\text{CE}} &= 3 \text{ V, Ic (set)} = 20 \text{ mA,} \\ f &= 2.0 \text{ GHz, Zs} = Z_{\text{Sopt, ZL}} = Z_{\text{Lopt}} \end{split}$	-	12.5	=	dBm
3rd Order Intermodulation Distortion Output Intercept Point	OIP <sub>3</sub>	$V_{CE} = 3 \text{ V, Ic } (\text{set}) = 20 \text{ mA,}$ $f = 2.0 \text{ GHz, } Z_S = Z_{Sopt}, Z_L = Z_{Lopt}$	-	24.0	=	dBm

**Notes 1.** Pulse measurement: PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2%

2. Collector to base capacitance when the emitter grounded

3. MSG = 
$$\frac{S_{21}}{S_{12}}$$

## **hfe CLASSIFICATION**

Rank	FB
Marking	zN
h <sub>FE</sub> Value	220 to 380

# **S-PARAMETERS**

S-parameters/Noise parameters are provided on the NEC Compound Semiconductor Devices Web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

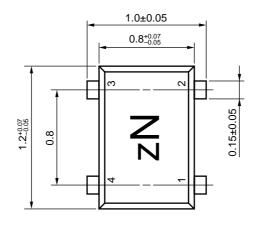
Click here to download S-parameters.

 $[\mathsf{RF} \ \mathsf{and} \ \mathsf{Microwave}] \to [\mathsf{Device} \ \mathsf{Parameters}]$ 

URL http://www.ncsd.necel.com/

# **PACKAGE DIMENSIONS**

# 4-PIN LEAD-LESS MINIMOLD (M14, 1208 PACKAGE) (UNIT: mm)





# **PIN CONNECTIONS**

- 1. Collector
- 2. Emitter
- 3. Base
- 4. NC (Connected with Pin 2)

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PBB	< 1000 PPM	Not Detected		
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